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Docket: 0756-1626

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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Divisional Patent Application of)
Shunpei YAMAZAKI et al.)
Based On Serial No. 08/213,837) Art Unit: 2503
Which Was Filed: March 16, 1994) Examiner: T. Arroyo
For: SEMICONDUCTOR DEVICE AND)
METHOD FOR FORMING THE)
SAME) Date: January 24, 1997

PRELIMINARY AMENDMENT

Honorable Assistant Commissioner for Patents
Washington, D.C. 20231

Sir:

Please preliminarily amend the subject application as follows:

IN THE CLAIMS:

Cancel claim 1 and add new claims 21-33 as follows:

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--21. An insulated gate field effect semiconductor device comprising:
source and drain semiconductor regions and a channel
semiconductor region in contact with said source and drain regions; and